

# **Excellent Integrated System Limited**

Stocking Distributor

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<u>Vishay Semiconductor/Diodes Division</u> <u>VS-201CNQ050PBF</u>

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### Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite

Datasheet of VS-201CNQ050PBF - MOD SCHOTTKY RECT 200V TO-244

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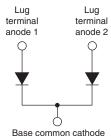


#### VS-201CNQ050PbF

Vishay Semiconductors

# Schottky Rectifier, 200 A





F	EΔ	TI	JR	ES

- 175 °C T<sub>J</sub> operation
- · Center tap module
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified for industrial level
- Material categorization: For definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

#### **DESCRIPTION**

The VS-201CNQ050PbF center tap Schottky rectifier module has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in high current switching power supplies, converters, freewheeling diodes, welding, and reverse battery protection.

PRODUCT SUMMARY				
I <sub>F(AV)</sub>	200 A			
$V_{R}$	50 V			

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I <sub>F(AV)</sub>	Rectangular waveform	200	А			
V <sub>RRM</sub>		50	V			
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	16 000	А			
V <sub>F</sub>	100 Apk, T <sub>J</sub> = 125 °C (per leg)	0.58	V			
T <sub>J</sub>	Range	- 55 to 175	°C			

VOLTAGE RATINGS					
PARAMETER	SYMBOL	201CNQ050PbF	UNITS		
Maximum DC reverse voltage	$V_{R}$	50	V		
Maximum working peak reverse voltage	$V_{RWM}$	50			

ABSOLUTE MAXIMUM RATINGS						
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average per device forward current See fig. 5 per leg		l . l		200	Α	
		I <sub>F(AV)</sub>	50 % duty cycle at T <sub>C</sub> = 146 °C, rectangular waveform		100	^
Maximum peak one cycle non-repetitive surge current per leg See fig. 7		I <sub>FSM</sub>	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with	16 000	А
			10 ms sine or 6 ms rect. pulse	rated V <sub>RRM</sub> applied	2000	
Non-repetitive avalanche energy per leg		E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 17 A, L = 1 mH		145	mJ
Repetitive avalanche current per leg		I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		20	Α

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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
	V <sub>FM</sub> <sup>(1)</sup>	100 A	- T <sub>J</sub> = 25 °C	0.67	V	
Maximum forward voltage drop per leg		200 A		0.81		
See fig. 1	VFM **/	100 A	- T <sub>.1</sub> = 125 °C	0.58		
		200 A	1J = 125 C	0.71		
Maximum reverse leakage current per leg	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	V <sub>B</sub> = Rated V <sub>B</sub>	10	· mA	
See fig. 2		T <sub>J</sub> = 125 °C	V <sub>R</sub> = nateu V <sub>R</sub>	90		
Maximum junction capacitance per leg	C <sub>T</sub>	V <sub>R</sub> = 5 V <sub>DC</sub> (test signal range 100 kHz to 1 MHz) 25 °C		5200	pF	
Typical series inductance per leg	L <sub>S</sub>	From top of terminal hole to mounting plane		7.0	nH	
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs	

#### Note

 $<sup>^{(1)}</sup>$  Pulse width < 300  $\mu$ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>	- 55	-	175	°C	
per leg	D	-	-	0.38		
Thermal resistance, junction to case per module	$R_{thJC}$	-	-	0.19	°C/W	
Thermal resistance, case to heatsink	R <sub>thCS</sub>	-	0.10	-		
Weight		-	68	-	g	
weignt			2.4		OZ.	
Mounting torque		35.4 (4)	-	53.1 (6)		
Mounting torque center hole		30 (3.4)	-	40 (4.6)	lbf ⋅ in (N ⋅ m)	
Terminal torque		30 (3.4)	-	44.2 (5)		
Vertical pull		-	-	80	llef in	
2" lever pull		-	-	35	- lbf · in	

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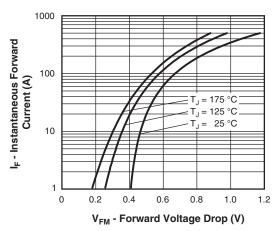


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

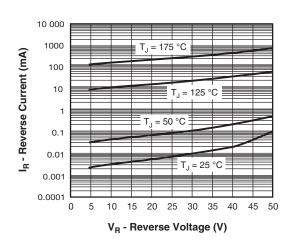


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

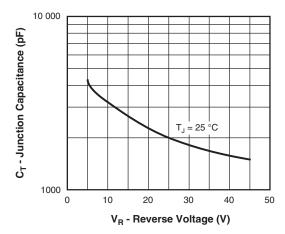


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

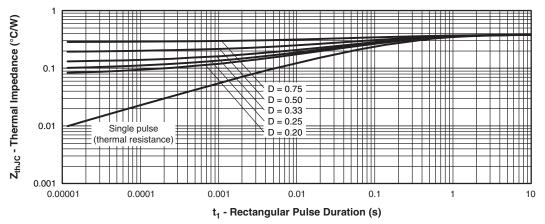


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics (Per Leg)

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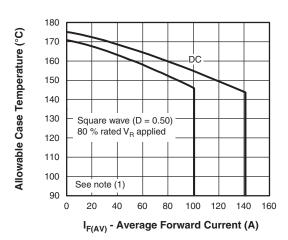


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

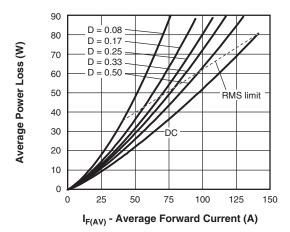


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

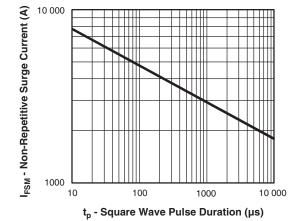


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

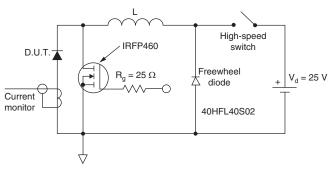


Fig. 8 - Unclamped Inductive Test Circuit

Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ; Pd = Forward power loss =  $I_{F(AV)} \times V_{FM}$  at ( $I_{F(AV)}/D$ ) (see fig. 6); Pd<sub>REV</sub> = Inverse power loss =  $V_{R1} \times I_{R}$  (1 - D);  $I_{R}$  at  $V_{R1}$  = 80 % rated  $V_{R}$ 

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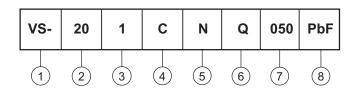


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#### **ORDERING INFORMATION TABLE**

**Device code** 



1 - Vishay Semiconductors product

Average current rating (x 10)

Product silicon identification

4 - C = Circuit configuration

5 - N = Not isolated

6 - Q = Schottky rectifier diode

7 - Voltage rating (050 = 50 V)

8 - Lead (Pb)-free

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.comdoc?95021			



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